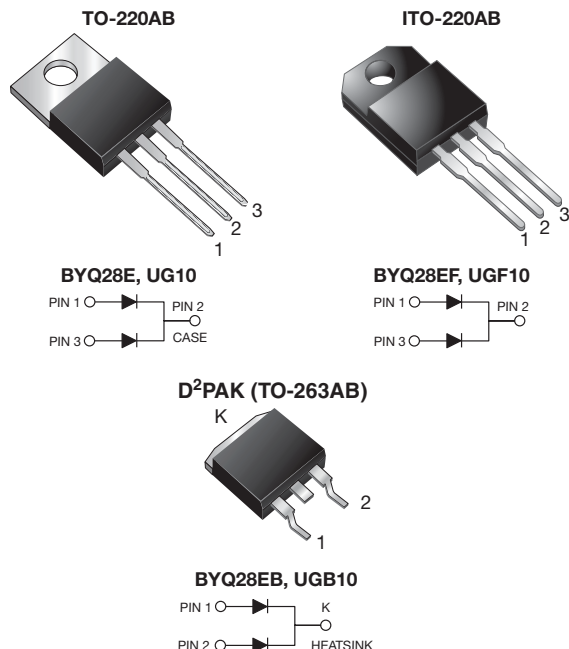


## Dual Common Cathode Ultrafast Rectifier


**RoHS**  
COMPLIANT

### FEATURES

- Power pack
- Glass passivated pellet chip junction
- Ultrafast recovery times
- Soft recovery characteristics
- Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C for D<sup>2</sup>PAK (TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
- Automotive ordering code: base P/NHE3 (for ITO-220AB and D<sup>2</sup>PAK (TO-263AB package))
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

### DESIGN SUPPORT TOOLS AVAILABLE



| PRIMARY CHARACTERISTICS |                                                    |
|-------------------------|----------------------------------------------------|
| $I_{F(AV)}$             | 2 x 5.0 A                                          |
| $V_{RRM}$               | 100 V to 200 V                                     |
| $I_{FSM}$               | 55 A                                               |
| $t_{rr}$                | 25 ns                                              |
| $V_F$                   | 0.895 V                                            |
| $T_J$ max.              | 150 °C                                             |
| Package                 | TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB) |
| Circuit configuration   | Common cathode                                     |

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB)  
Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS-compliant, commercial grade  
Base P/NHE3\_X - RoHS-compliant and AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B,...)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

**Polarity:** as marked

**Mounting Torque:** 10 in-lbs max.

| MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)                                  |                                   |             |            |            |      |
|--------------------------------------------------------------------------------------------------|-----------------------------------|-------------|------------|------------|------|
| PARAMETER                                                                                        | SYMBOL                            | UG10BCT     | UG10CCT    | UG10DCT    | UNIT |
|                                                                                                  |                                   | BYQ28E-100  | BYQ28E-150 | BYQ28E-200 |      |
| Maximum repetitive peak reverse voltage                                                          | V <sub>RRM</sub>                  | 100         | 150        | 200        | V    |
| Working peak reverse voltage                                                                     | V <sub>RWM</sub>                  | 100         | 150        | 200        | V    |
| Maximum DC blocking voltage                                                                      | V <sub>DC</sub>                   | 100         | 150        | 200        | V    |
| Maximum average forward rectified current at T <sub>C</sub> = 100 °C — total device<br>per diode | I <sub>F(AV)</sub>                | 10          |            |            | A    |
|                                                                                                  |                                   | 5.0         |            |            |      |
| Peak forward surge current 8.3 ms single half sine-wave                                          | I <sub>FSM</sub>                  | 55          |            |            | A    |
| Non-repetitive peak reverse current per diode at t <sub>p</sub> = 100 μs                         | I <sub>RSM</sub>                  | 0.2         |            |            | A    |
| Electrostatic discharge capacitor voltage,<br>human body model: C = 250 pF, R = 1.5 kΩ           | V <sub>C</sub>                    | 8           |            |            | kV   |
| Operating junction and storage temperature range                                                 | T <sub>J</sub> , T <sub>STG</sub> | -40 to +150 |            |            | °C   |
| Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min                           | V <sub>AC</sub>                   | 1500        |            |            | V    |



| ELECTRICAL CHARACTERISTICS ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                                                                                                                |                                     |             |       |               |
|-----------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------|-------------------------------------|-------------|-------|---------------|
| PARAMETER                                                                               | TEST CONDITIONS                                                                                                |                                     | SYMBOL      | VALUE | UNIT          |
| Maximum instantaneous forward voltage per diode                                         | $I_F = 10\text{ A}$                                                                                            | $T_J = 25\text{ }^{\circ}\text{C}$  | $V_F^{(1)}$ | 1.25  | V             |
|                                                                                         | $I_F = 5\text{ A}$                                                                                             | $T_J = 150\text{ }^{\circ}\text{C}$ |             | 1.10  |               |
|                                                                                         |                                                                                                                | $T_J = 150\text{ }^{\circ}\text{C}$ |             | 0.895 |               |
| Maximum reverse current per diode at working peak reverse voltage                       |                                                                                                                | $T_J = 25\text{ }^{\circ}\text{C}$  | $I_R$       | 10    | $\mu\text{A}$ |
|                                                                                         |                                                                                                                | $T_J = 100\text{ }^{\circ}\text{C}$ |             | 200   |               |
|                                                                                         |                                                                                                                | $T_J = 100\text{ }^{\circ}\text{C}$ |             |       |               |
| Maximum reverse recovery time per diode                                                 | $I_F = 1.0\text{ A}$ , $dI/dt = 100\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ , $I_{rr} = 0.1\text{ I}_{RM}$ |                                     | $t_{rr}$    | 25    | ns            |
| Maximum reverse recovery time per diode                                                 | $I_F = 0.5\text{ A}$ , $I_R = 1.0\text{ A}$ , $I_{rr} = 0.25\text{ A}$                                         |                                     | $t_{rr}$    | 20    | ns            |
| Maximum stored charge per diode                                                         | $I_F = 2\text{ A}$ , $dI/dt = 20\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ , $I_{rr} = 0.1\text{ I}_{RM}$    |                                     | $Q_{rr}$    | 9     | nC            |

**Note**

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                 |        |         |         |                             |
|--------------------------------------------------------------------------------------|-----------------|--------|---------|---------|-----------------------------|
| PARAMETER                                                                            | SYMBOL          | UG10   | UGF10   | UGB10   | UNIT                        |
|                                                                                      |                 | BYQ28E | BYQ28EF | BYQ28EB |                             |
| Typical thermal resistance per diode, junction to ambient                            | $R_{\theta JA}$ | 50     | 55      | 50      | $^{\circ}\text{C}/\text{W}$ |
| Typical thermal resistance per diode, junction to case                               | $R_{\theta JC}$ | 4.5    | 6.7     | 4.8     |                             |

| ORDERING INFORMATION (Example) |                                   |                 |              |               |               |
|--------------------------------|-----------------------------------|-----------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N                     | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB                       | BYQ28E-200-E3/45                  | 1.80            | 45           | 50/tube       | Tube          |
| ITO-220AB                      | BYQ28EF-200-E3/45                 | 1.95            | 45           | 50/tube       | Tube          |
| D <sup>2</sup> PAK (TO-263AB)  | BYQ28EB-200-E3/45                 | 1.77            | 45           | 50/tube       | Tube          |
| D <sup>2</sup> PAK (TO-263AB)  | BYQ28EB-200-E3/81                 | 1.77            | 81           | 800/reel      | Tape and reel |
| ITO-220AB                      | BYQ28EF-200HE3_A/P <sup>(1)</sup> | 1.95            | P            | 50/tube       | Tube          |
| D <sup>2</sup> PAK (TO-263AB)  | BYQ28EB-200HE3_A/P <sup>(1)</sup> | 1.95            | P            | 50/tube       | Tube          |
| D <sup>2</sup> PAK (TO-263AB)  | BYQ28EB-200HE3_A/I <sup>(1)</sup> | 1.95            | I            | 800/reel      | Tape and reel |

**Note**

(2) AEC-Q101 qualified, available in ITO-220AB and D<sup>2</sup>PAK (TO-263AB) package

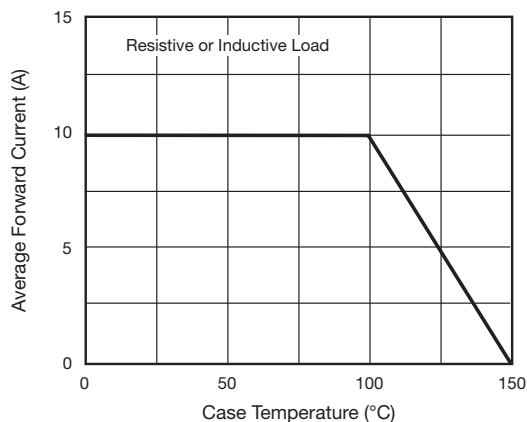
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

Fig. 1 - Forward Current Derating Curve

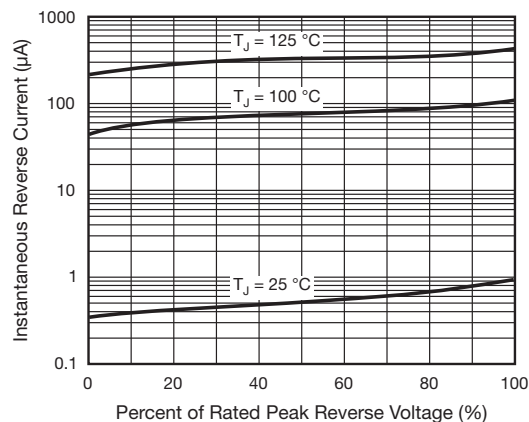


Fig. 4 - Typical Reverse Characteristics Per Diode

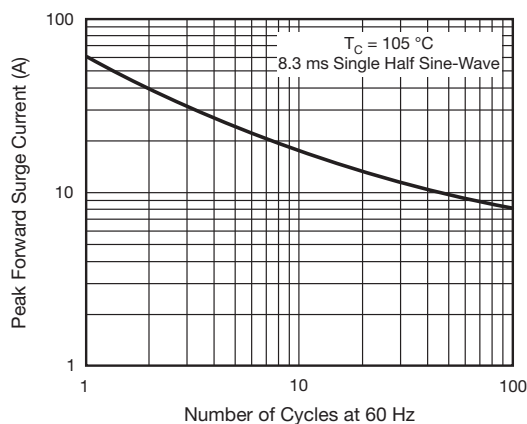


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

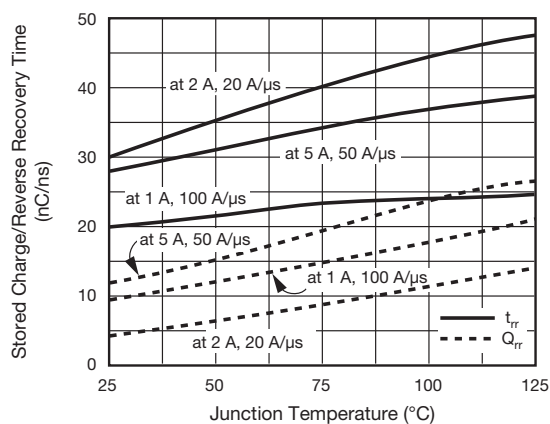


Fig. 5 - Reverse Switching Characteristics Per Diode

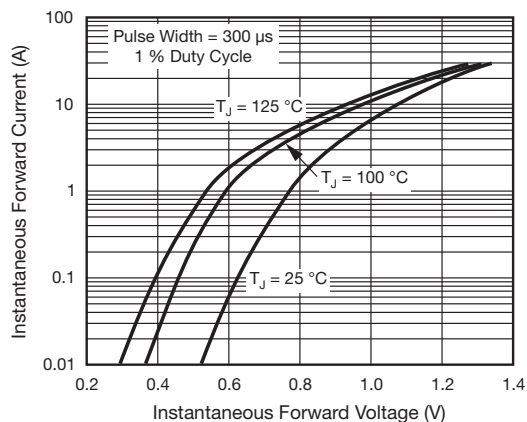


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

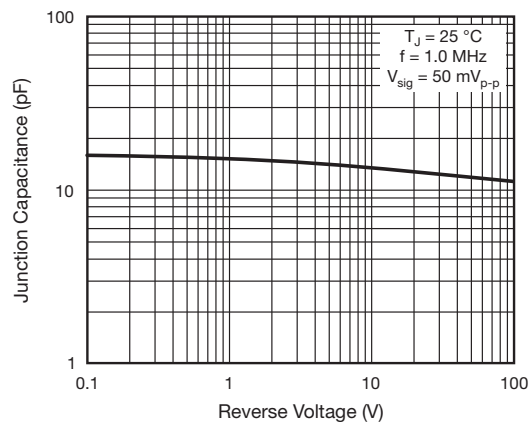
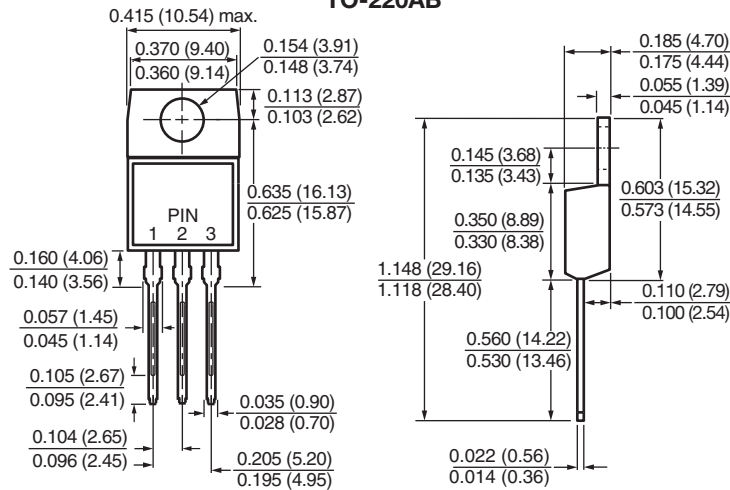


Fig. 6 - Typical Junction Capacitance Per Diode

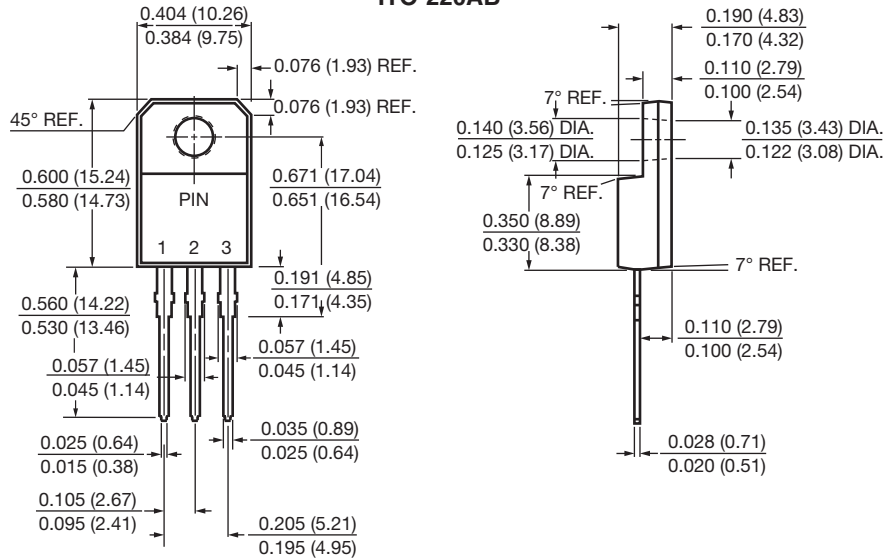


**PACKAGE OUTLINE DIMENSION** in inches (millimeters)

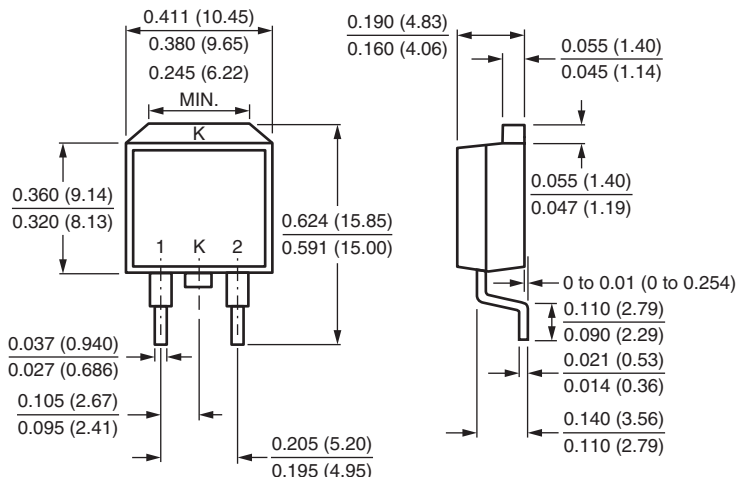
**TO-220AB**



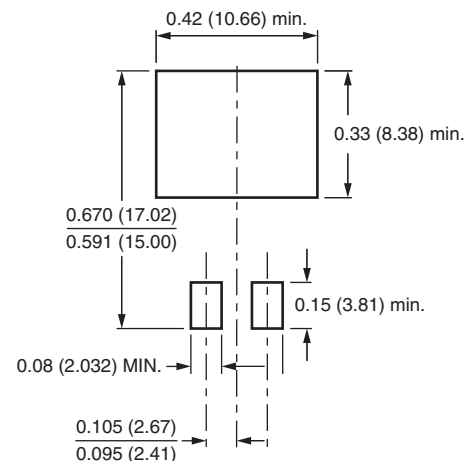
**ITO-220AB**



**D<sup>2</sup>PAK (TO-263AB)**



**Mounting Pad Layout**





## Disclaimer

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